

HD74HC540/HD74HC541

Octal Buffers/Line Drivers (with 3-state outputs)

HITACHI

Description

The HD74HC540 is an inverting buffer and the HD74HC541 is a non-inverting buffer. The 3-state control gate operates as a two-input NOR such that if either $\overline{G}_1$ or $\overline{G}_2$ are high, all eight outputs are in the high-impedance state.

Features

- High Speed Operation: $t_{pd} = 11.5 \text{ ns typ (} C_L = 50 \text{ pF)}$
- High Output Current: Fanout of 15 LSTTL Loads
- Wide Operating Voltage: $V_{CC} = 2 \text{ to } 6 \text{ V}$
- Low Input Current: $1 \text{ }\mu\text{A max}$
- Low Quiescent Supply Current: $I_{CC} \text{ (static)} = 4 \text{ }\mu\text{A max (} T_a = 25^\circ\text{C)}$

Function Table

Inputs			Output Y	
$\overline{G}_1$	$\overline{G}_2$	A	HD74HC540	HD74HD541
L	L	L	H	L
L	L	H	L	H
H	X	X	Z	Z
X	H	X	Z	Z

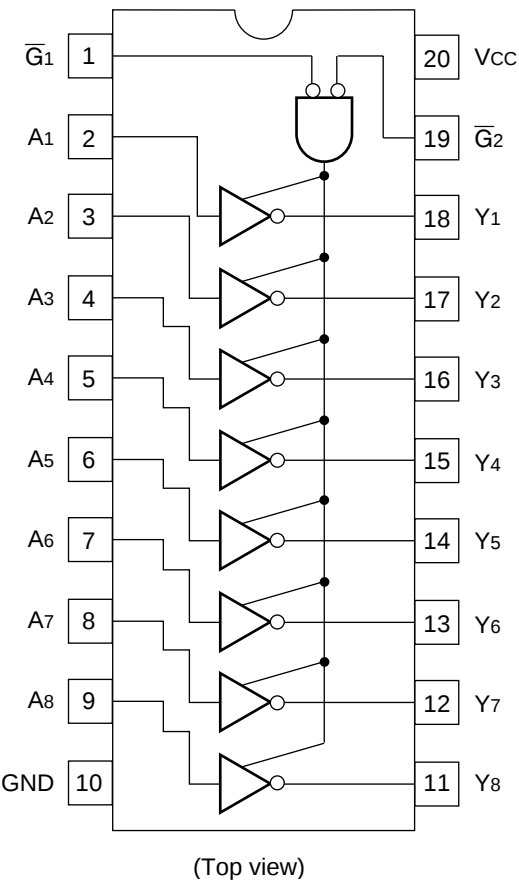
- X : irrelevant
Z : off (high-impedance) state of a 3-state output.



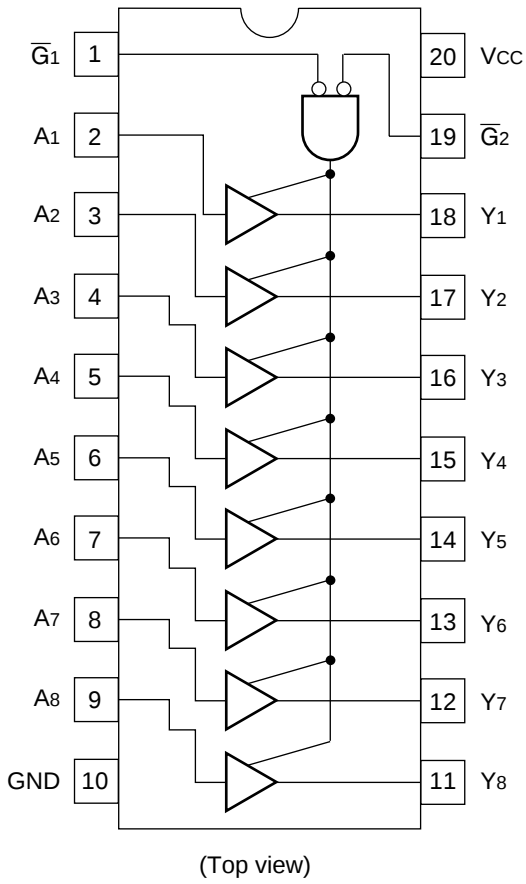
HD74HC540/HD74HC541

Pin Arrangement

HD74HC540



HD74HC541



Absolute Maximum Ratings

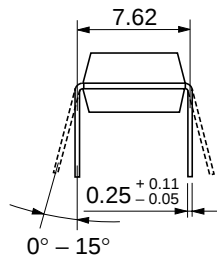
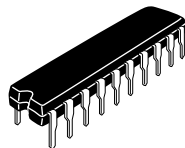
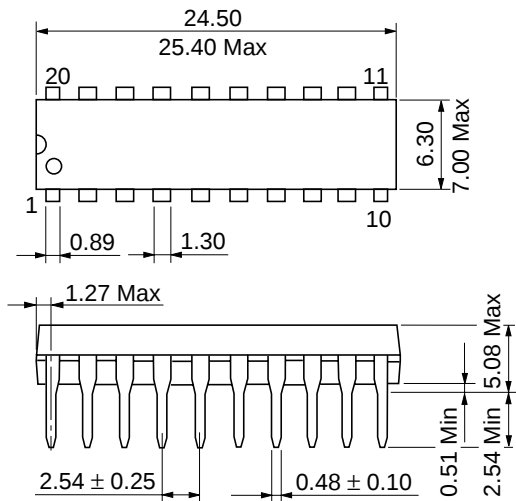
Item	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5 to +7.0	V
Input voltage	V_{IN}	-0.5 to $V_{CC} + 0.5$	V
Output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Output current	I_{OUT}	± 35	mA
DC current drai per V_{CC} GND	I_{CC}, I_{GND}	± 75	mA
DC input diode current	I_{IK}	± 20	mA
DC output diode current	I_{OK}	± 20	mA
Power Dissipation per package	P_T	500	mW
Storage temperature	Tstg	-65 to +150	$^{\circ}C$

DC Characteristics

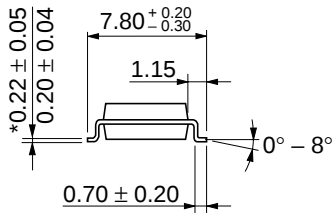
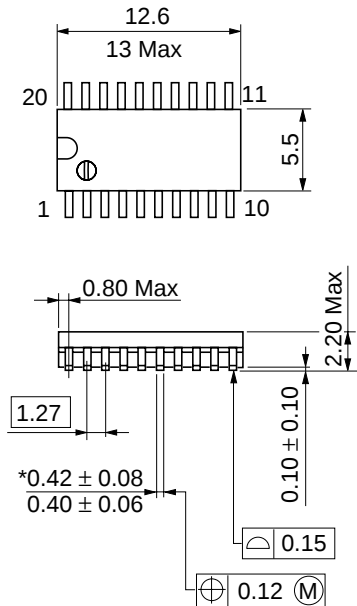
Item	Symbol	V _{CC} (V)	Ta = 25°C			Ta = -40 to +85°C		Unit	Test Conditions	
			Min	Typ	Max	Min	Max			
Input voltage	V _{IH}	2.0	1.5	—	—	1.5	—	V		
		4.5	3.15	—	—	3.15	—			
		6.0	4.2	—	—	4.2	—			
	V _{IL}	2.0	—	—	0.3	—	0.3	V		
		4.5	—	—	1.35	—	1.35			
		6.0	—	—	1.8	—	1.8			
Hysteresis voltage	V _H	2.0	—	0.1	—	—	—	V		
		4.5	—	0.4	—	—	—			
		6.0	—	0.4	—	—	—			
Output voltage	V _{OH}	2.0	1.9	2.0	—	1.9	—	V	Vin = V _{IH} or V _{IL} I _{OH} = -20 μA	
		4.5	4.4	4.5	—	4.4	—			
		6.0	5.9	6.0	—	5.9	—			
		4.5	4.18	—	—	4.13	—			I _{OH} = -6 mA
		6.0	5.68	—	—	5.63	—			I _{OH} = -7.8 mA
	V _{OL}	2.0	—	0.0	0.1	—	0.1	V	Vin = V _{IH} or V _{IL} I _{OL} = 20 μA	
		4.5	—	0.0	0.1	—	0.1			
		6.0	—	0.0	0.1	—	0.1			
		4.5	—	—	0.26	—	0.33			I _{OL} = 6 mA
		6.0	—	—	0.26	—	0.33			I _{OL} = 7.8 mA
Off-state output current	I _{OZ}	6.0	—	—	±0.5	—	±5.0	μA	Vin = V _{IH} or V _{IL} , Vout = V _{CC} or GND	
Input current	I _{in}	6.0	—	—	±0.1	—	±1.0	μA	Vin = V _{CC} or GND	
Quiescent supply current	I _{CC}	6.0	—	—	4.0	—	40	μA	Vin = V _{CC} or GND, Iout = 0 μA	

AC Characteristics (C_L = 50 pF, Input t_r = t_f = 6 ns)

Item	Symbol	V _{CC} (V)	Ta = 25°C			Ta = -40 to +85°C		Unit	Test Conditions
			Min	Typ	Max	Min	Max		
Propagation delay time	t _{PLH}	2.0	—	—	100	—	125	ns	(HD74HC540 only)
	t _{PHL}	4.5	—	11	20	—	25		
		6.0	—	—	17	—	21		
	t _{PLH}	2.0	—	—	115	—	145	ns	(HD74HC541 only)
	t _{PHL}	4.5	—	12	23	—	29		
		6.0	—	—	20	—	25		
Output enable time	t _{ZH}	2.0	—	—	150	—	190	ns	
	t _{ZL}	4.5	—	14	30	—	38		
		6.0	—	—	26	—	33		
Output disable time	t _{HZ}	2.0	—	—	150	—	190	ns	
	t _{LZ}	4.5	—	16	30	—	38		
		6.0	—	—	26	—	33		
Output rise/fall time	t _{TLH}	2.0	—	—	60	—	75	ns	
	t _{THL}	4.5	—	4	12	—	15		
		6.0	—	—	10	—	13		
Input capacitance	C _{in}	—	—	5	10	—	10	pF	

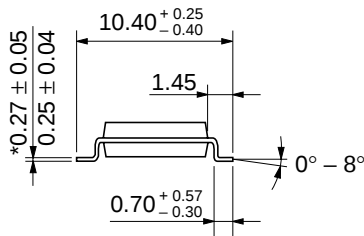
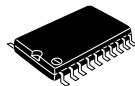
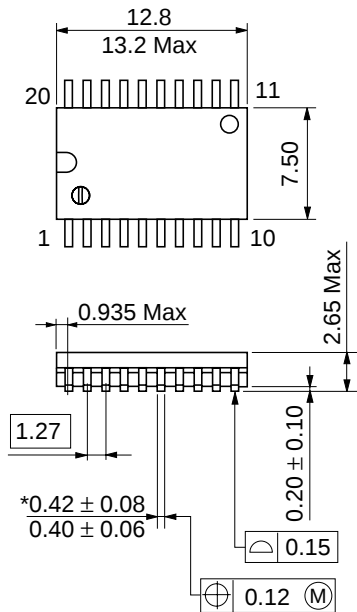


Hitachi Code	DP-20N
JEDEC	—
EIAJ	Conforms
Weight (reference value)	1.26 g



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-20DA
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.31 g



Hitachi Code	FP-20DB
JEDEC	Conforms
EIAJ	—
Weight (reference value)	0.52 g

*Dimension including the plating thickness
Base material dimension

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